



M T B F

(E I A J R C R - 9 1 0 2)

Model	MGFS3483R3
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	3	0.0720	
2		Hybrid	0	0.0000	
3	Transistors		3	0.1991	
4	Diodes		7	0.1350	
5	LED•Optocouplers		1	0.0700	
6	Resistors		24	0.0048	
7	Capacitors		18	0.1332	
8	Transformer•Choke Coil		1	0.0000	
9	Connectors		135	0.0184	
10	Others		2	0.2200	
Total Failure Rate [10 ⁻⁶ /H]				0.8525	

M T B F	[H]	1,173,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—